

세라믹 RF 부품의 모듈화 동향

2001. 11. 09

전자부품연구원 고주파재료연구센터 강남기

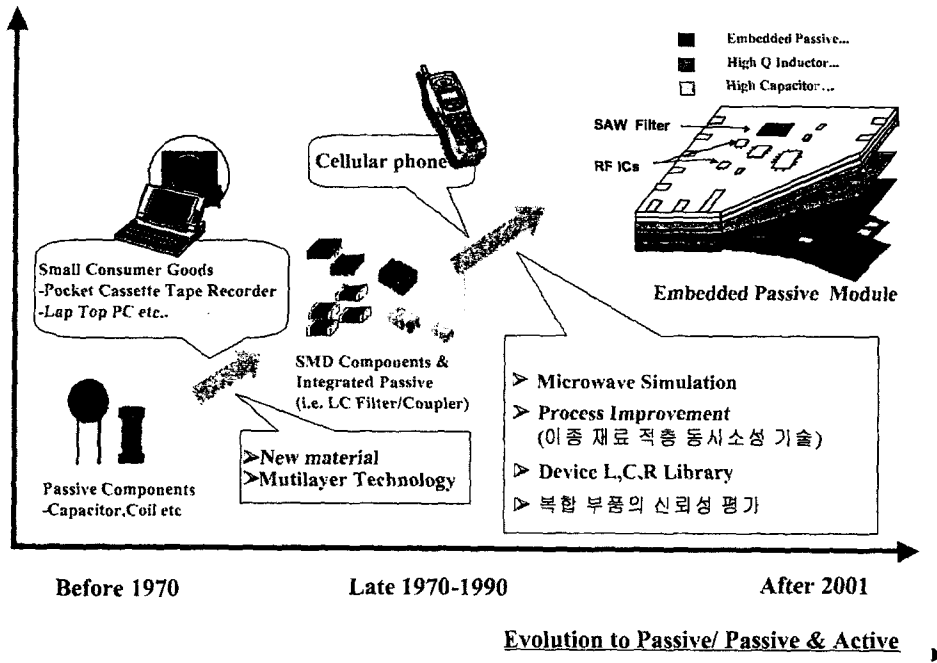
Tel : 031-6104-381, e-mail : kangnk@nuri.keti.re.kr



Contents

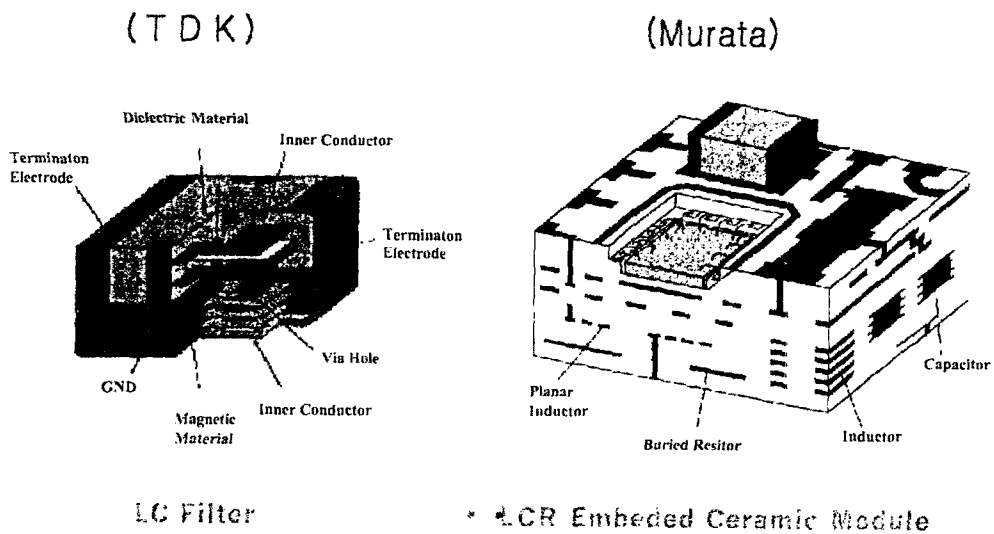
1. Introduction to ceramic RF modules
2. Embedded passives
3. Fabrication of multilayer ceramic modules
4. Applications

Component integration trend



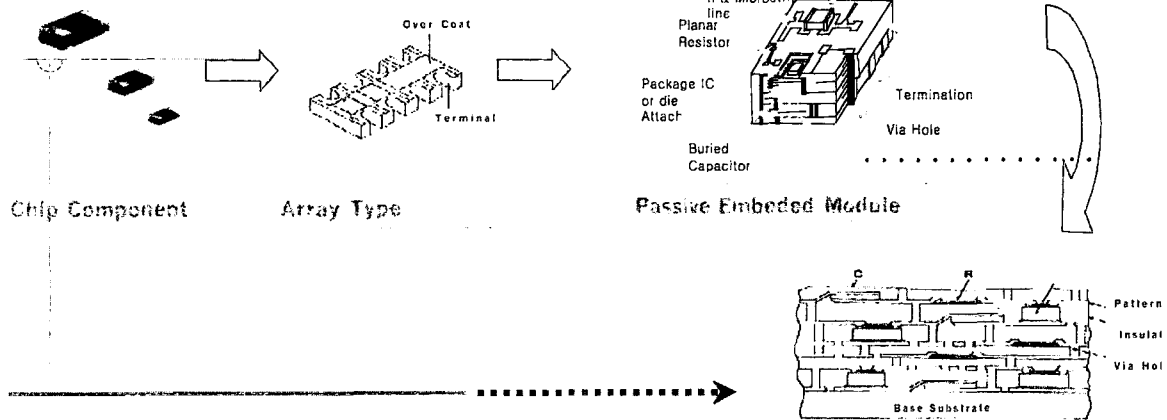
KETI 전자부품연구원
 Korea Electronics Technology Institute

Embedded type ceramic modules

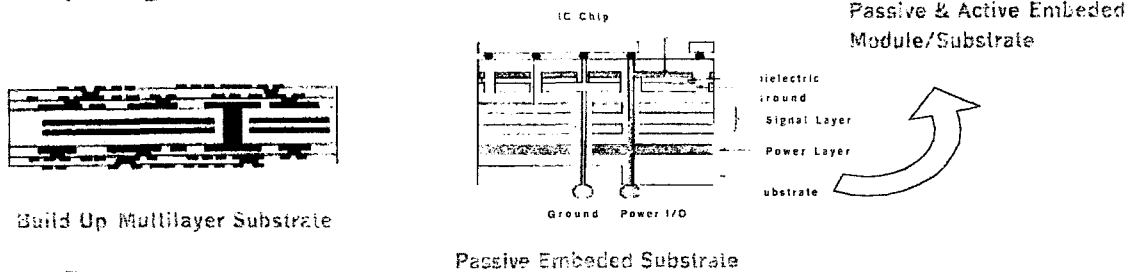


KETI 전자부품연구원
 Korea Electronics Technology Institute

(Integrated Passive Devices)

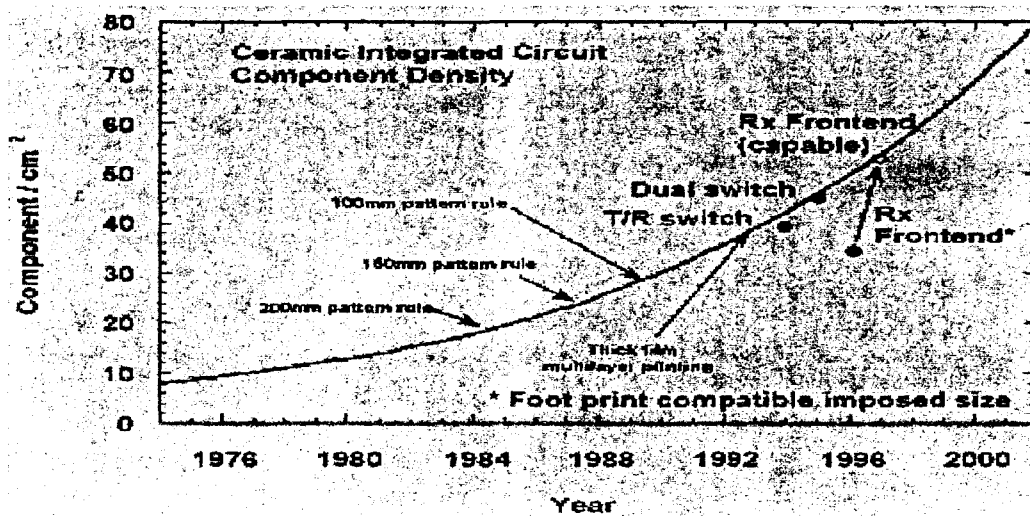


(Integral Substrates)



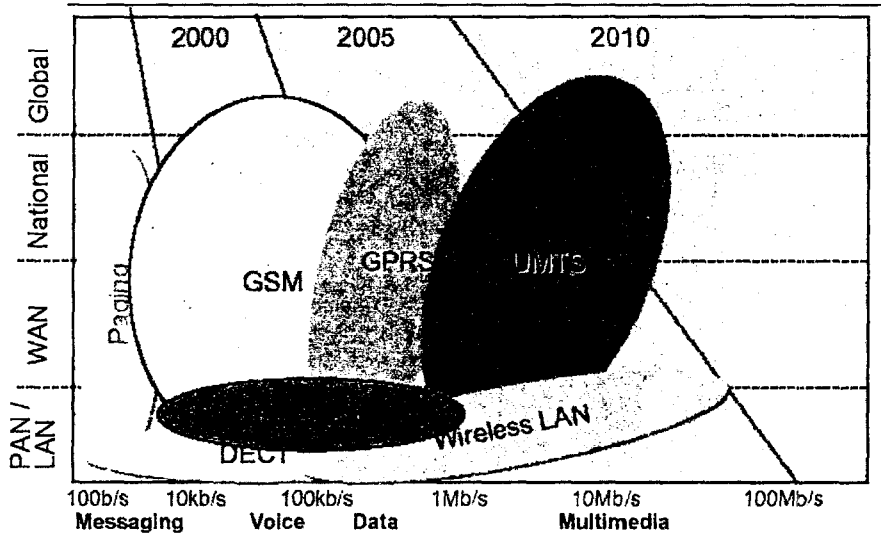
KE TI 전자부품연구원
Korea Electronics Technology Institute

Ceramic integrated circuit component density trend



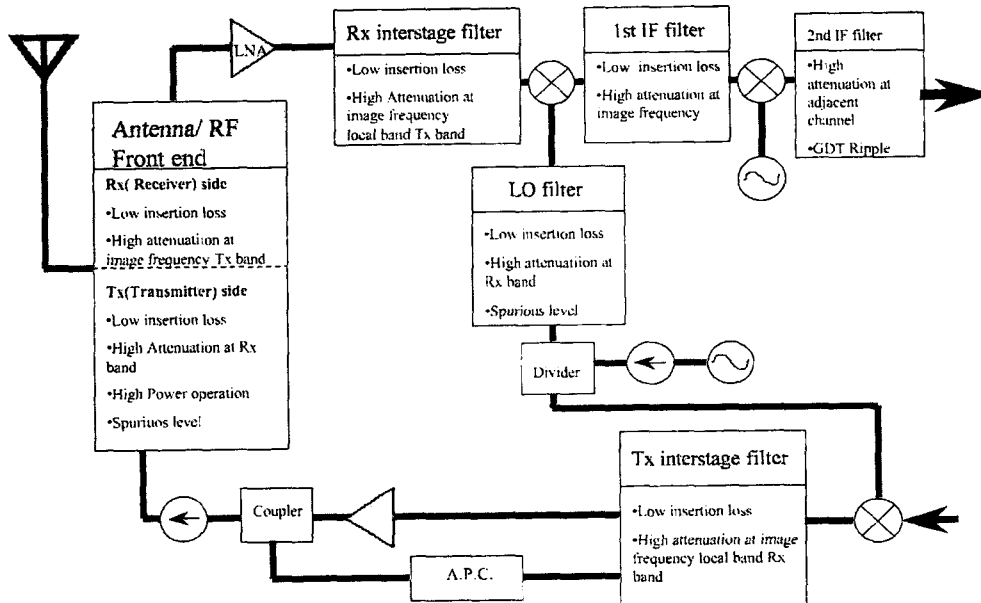
KE TI 전자부품연구원
Korea Electronics Technology Institute

Development trend of telecommunications



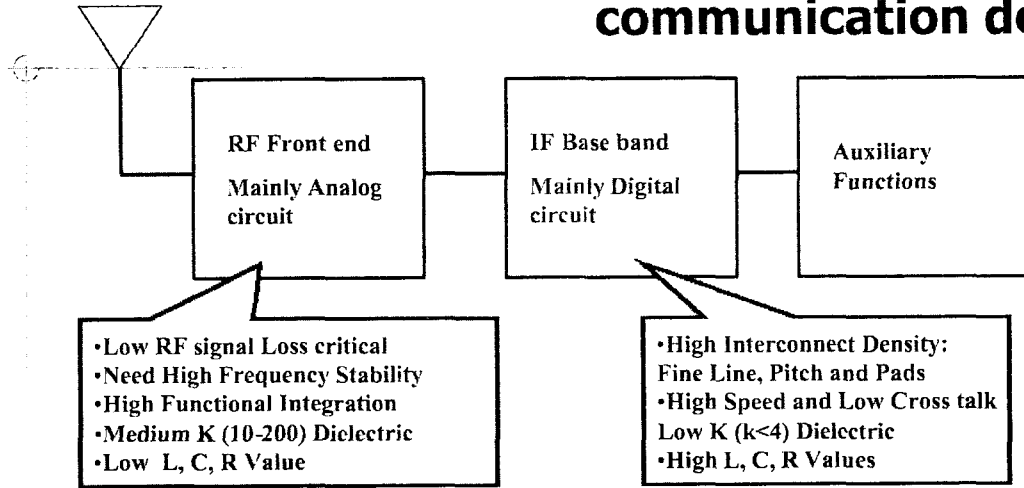
KE TI 전자부품연구원
Korea Electronics Technology Institute

RF/IF filter blocks and their typical design targets



KE TI 전자부품연구원
Korea Electronics Technology Institute

Conceptual diagram of a wireless communication device



- Low RF signal Loss critical
- Need High Frequency Stability
- High Functional Integration
- Medium K (10-200) Dielectric
- Low L, C, R Value

- High Interconnect Density: Fine Line, Pitch and Pads
- High Speed and Low Cross talk
- Low K ($k < 4$) Dielectric
- High L, C, R Values

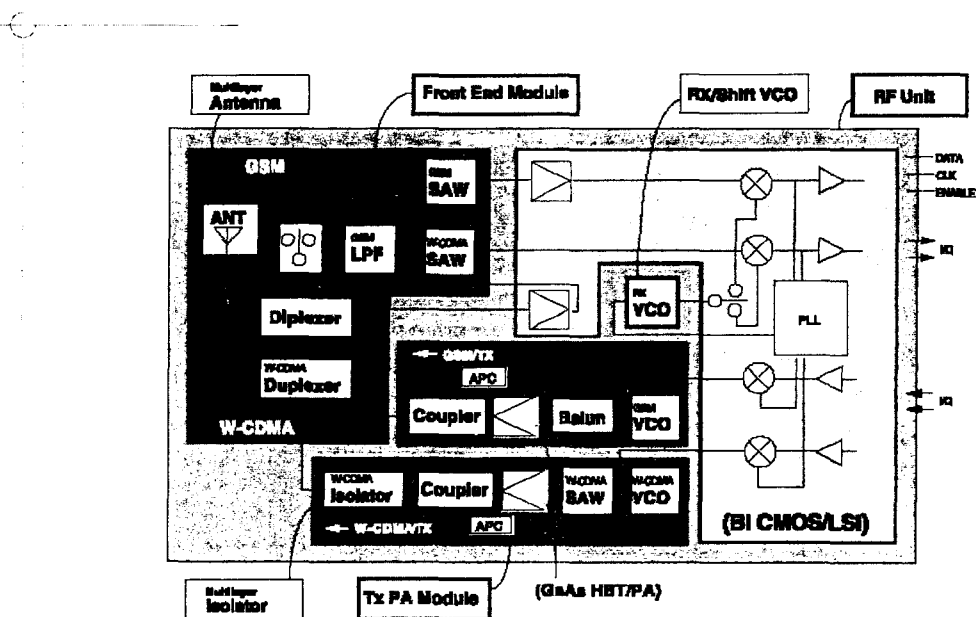
Special Ceramic Components

- Filter
- Isolator
- VCO
- Balun Transformer
- PAM

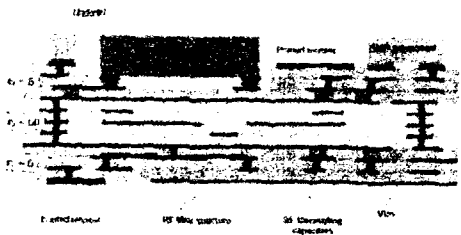
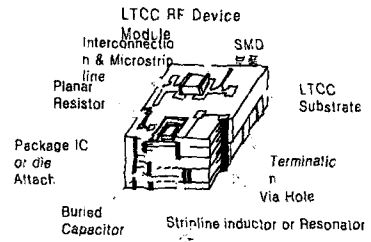
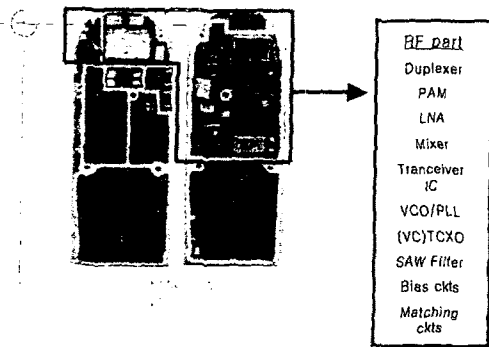
Ceramic Chip Components

- Capacitor,
- Resistor,
- Inductor,
- Substrate
- .. Etc

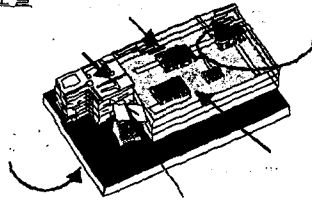
Integration trend for WCDMA/GSM dual mode



Dual band RF ceramic module

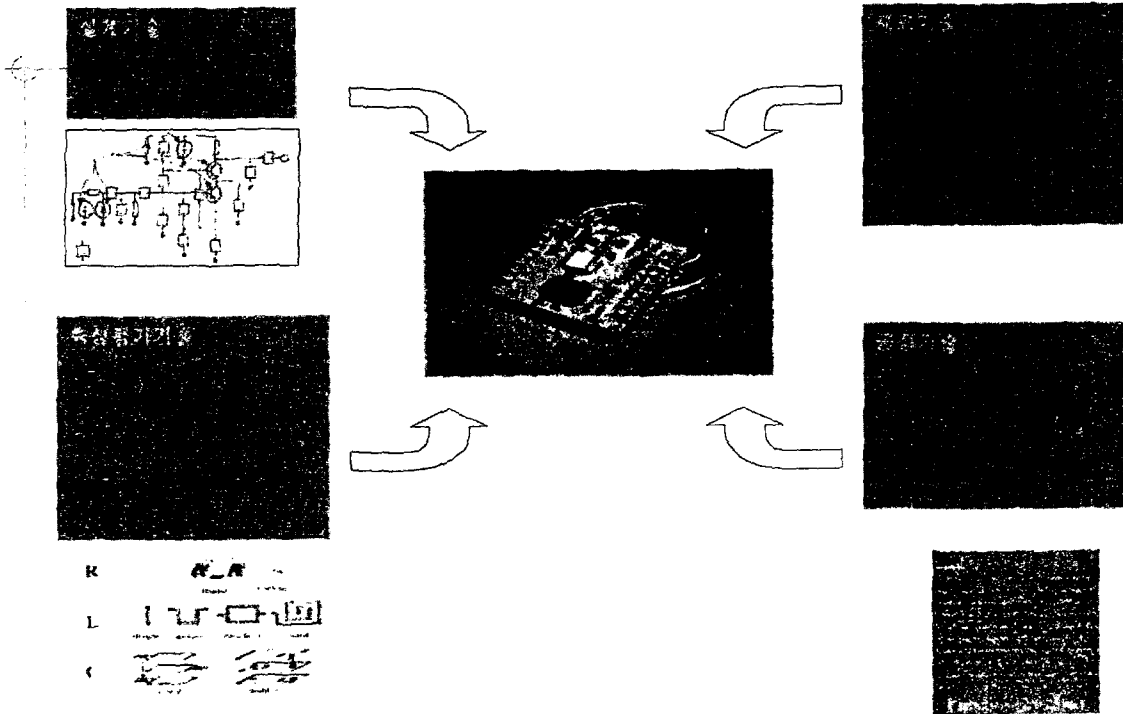


GSM/DCS 듀얼밴드 적층 세라믹 RF 모듈



KEITI 전자부품연구원
Korea Electronic Technology Institute

Related Technologies



KEITI 전자부품연구원
Korea Electronic Technology Institute

Process Flow

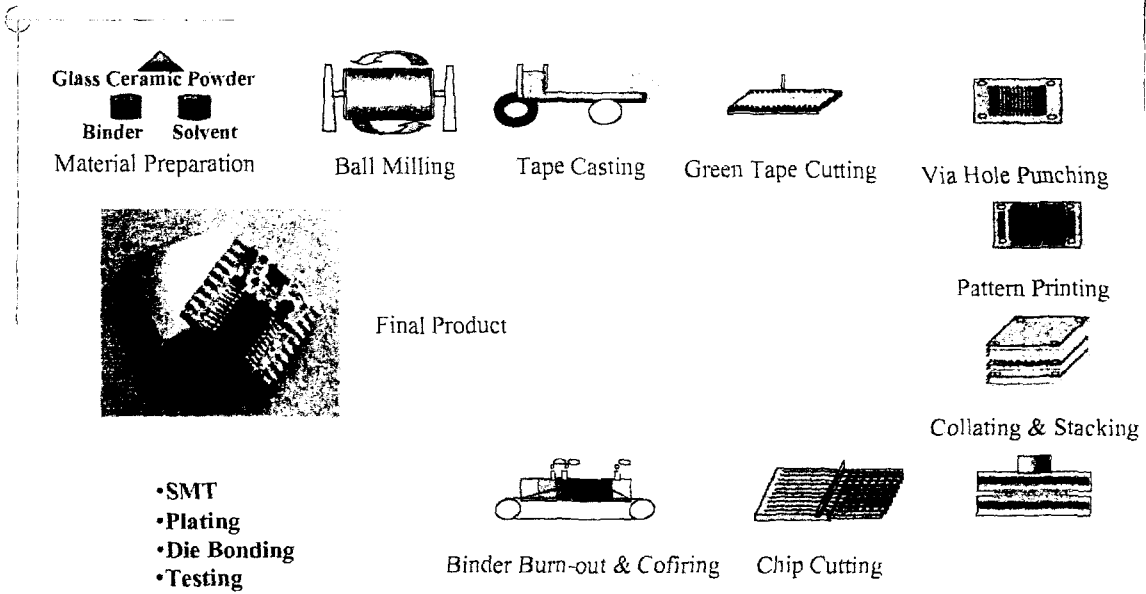
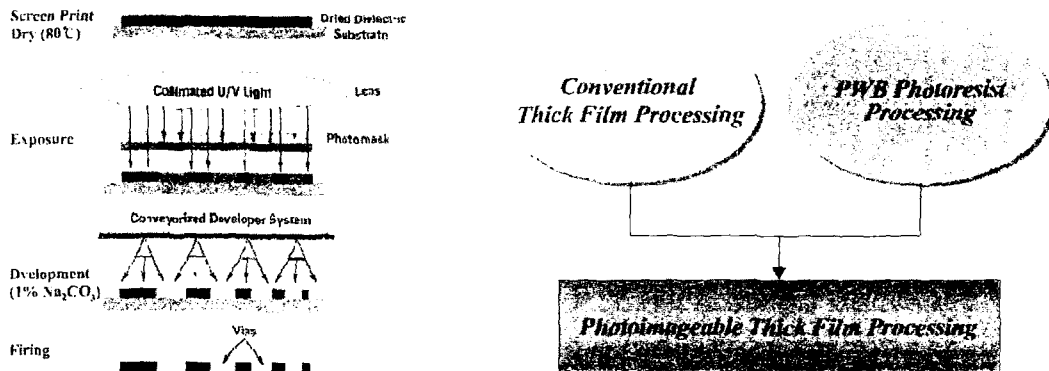
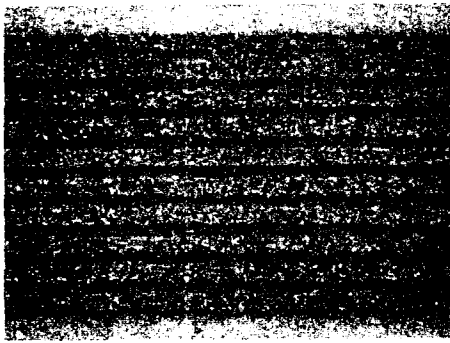


Photo-patterned fine line formation process

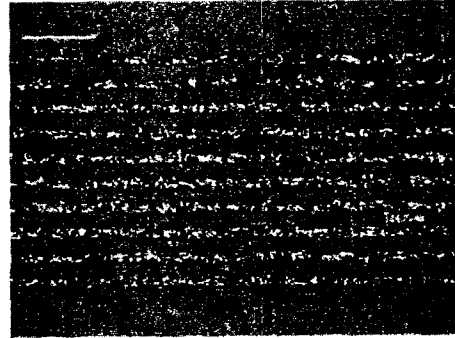


Photographs of fine line patterns

25 μm line/space pattern (after cofiring)

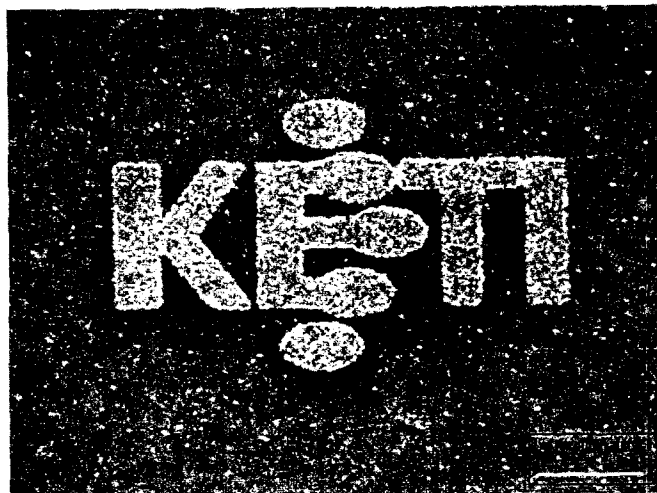


(a) after developing

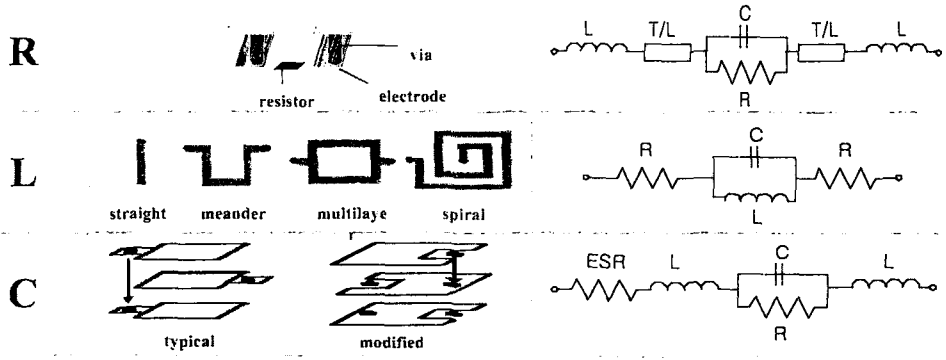


(b) after cofiring

Photographs of fine line patterns



R, L, C library for ceramic module

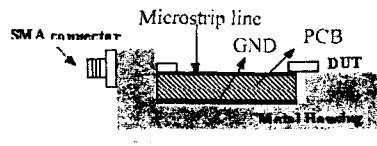


Simulation

S/W : Sonnet 5.1

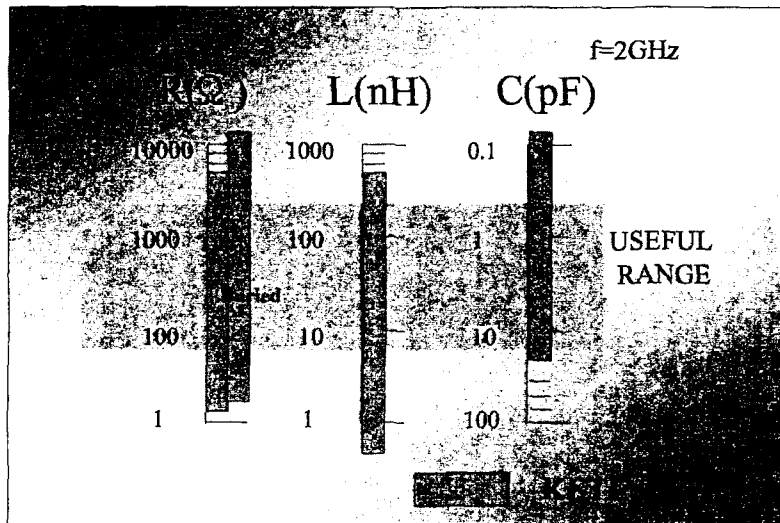


Measurement (100MHz ~ 6GHz)

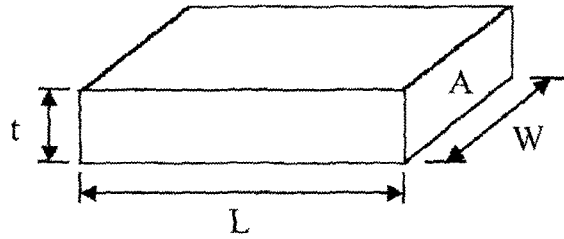


Instrument : HP 8753D Network analyzer

Component values for RF applications



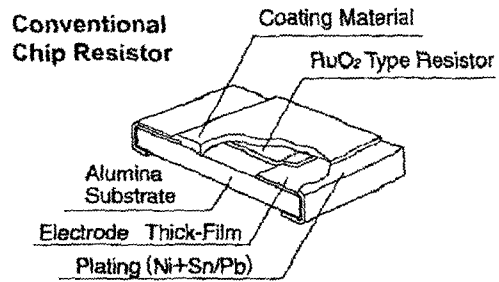
Resistor



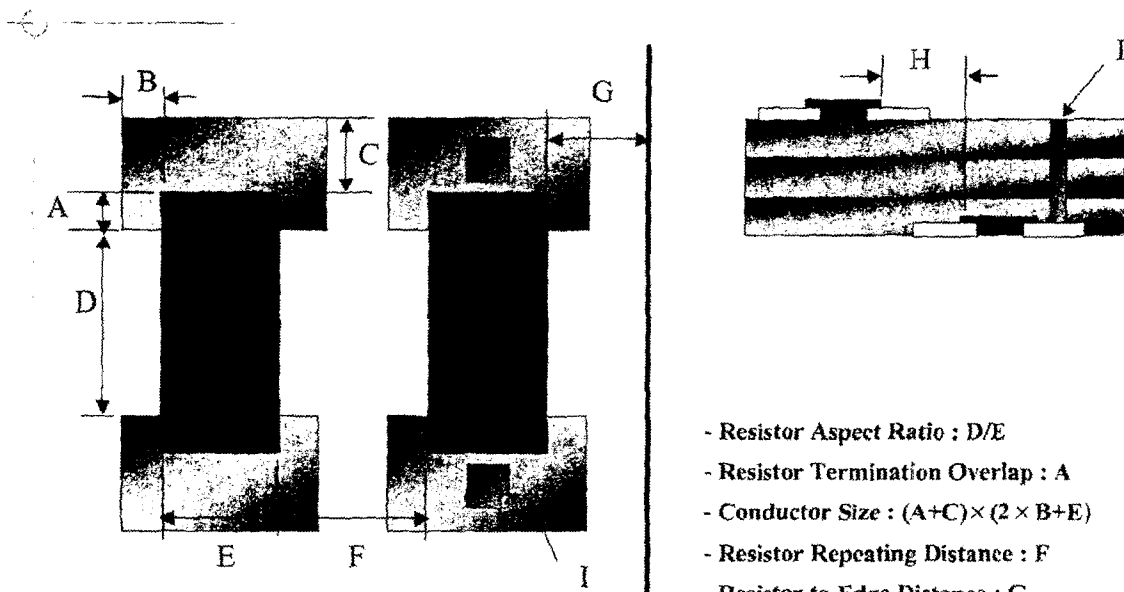
$$R = \frac{\rho \cdot L}{A} = \frac{\rho}{t} \cdot \frac{L}{W} = \rho_s \frac{L}{W}$$

$\rho_s = \text{Sheet Resistivity } (\Omega/\text{sq})$

$\frac{L}{W} = \frac{\text{Length}}{\text{Width}} = \text{Number of Squares}$
(Aspect Ratio)



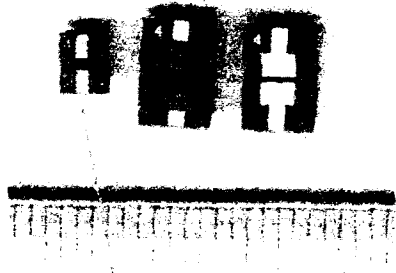
Resistor : design factors



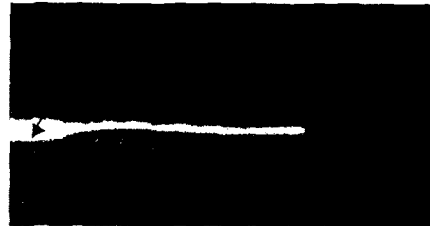
- Resistor Aspect Ratio : D/E
- Resistor Termination Overlap : A
- Conductor Size : $(A+C) \times (2 \times B+E)$
- Resistor Repeating Distance : F
- Resistor to Edge Distance : G
- Spacing between different tape layer : H
- Via effect : I

Resistor : top and buried

Buried Resistor without Via



Buried Resistor 단면



Buried Resistor with Via



Top Resistor

KE TI 전자부품연구원
Korea Electronics Technology Institute

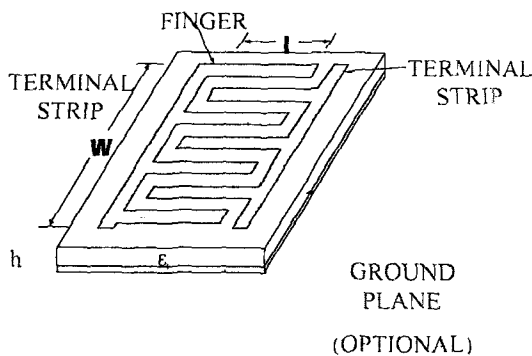
Capacitor design

Type 1

$$C = \frac{A \cdot \epsilon_r \cdot (N-1)}{4.45 \cdot D} \text{ pF}$$

N=total number of plates
 ϵ_r = Relative Dielectric constant
 A=Area of plate-Sq. In.
 D=Distance between plates-In.

Type 2

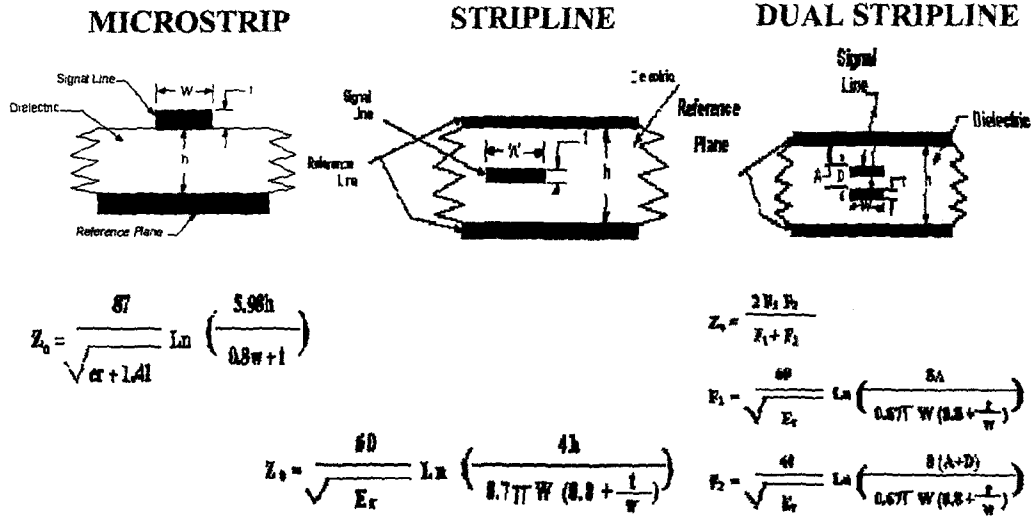


$$C = \frac{\epsilon_r + 1}{w} l [(n-3)A_1 + A_2]$$

N=number of fingers
 $A_1=0.089 \text{ pF/cm}$ for $h>w$
 $A_2=0.1 \text{ pF/cm}$ for $h>w$
 l= finger length, cm
 w=finger width
 h=Dielectric thickness, cm

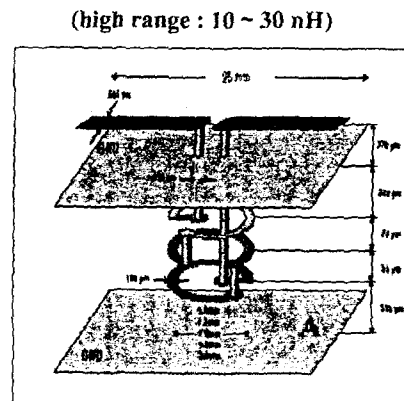
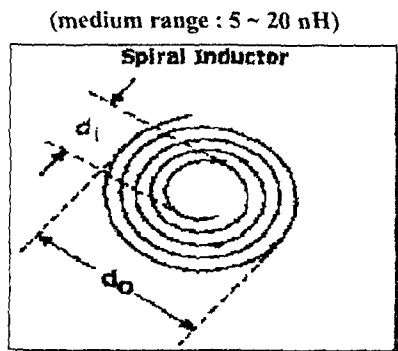
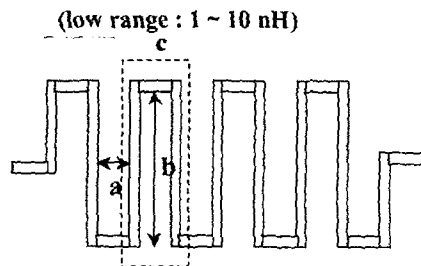
KE TI 전자부품연구원
Korea Electronics Technology Institute

Impedance choice



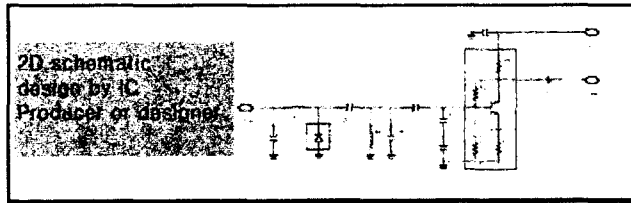
KE TI 전자부품연구원
Korea Electronic Technology Institute

Inductor design

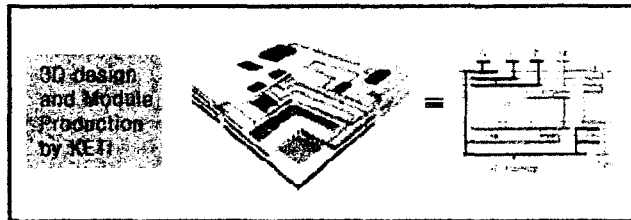


KE TI 전자부품연구원
Korea Electronic Technology Institute

Process for multilayer ceramic RF module design

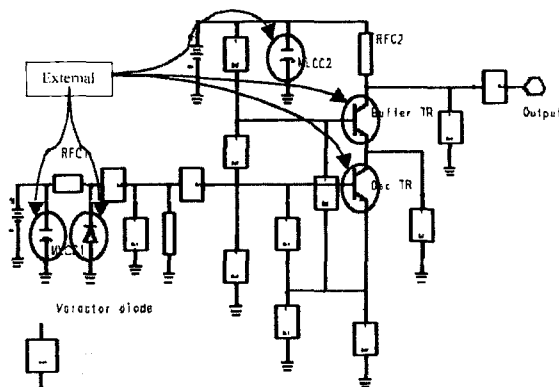


Simulation
: ADS, Serenade

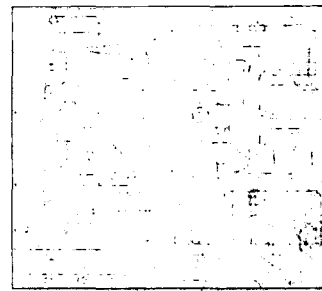


3D Layout
: HFSS, Sonnet

VCO circuit design

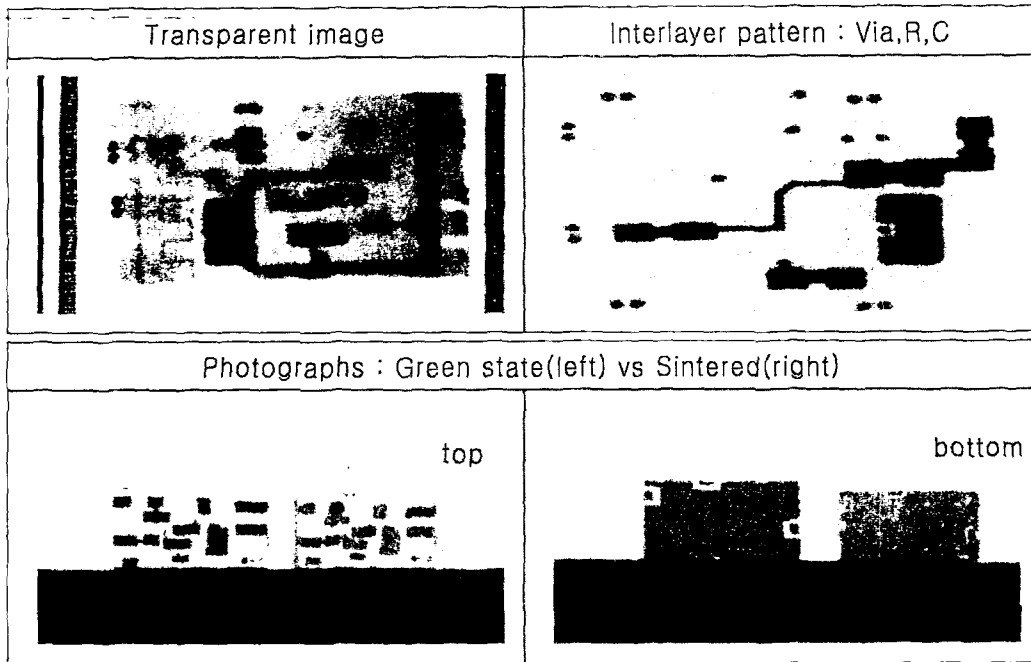


3-D Circuit Design Layout



- Total components = 21 , Layer : 12
- External : TR(2), diode(1), bypass cap.(2) : 24%, but some components may be added for tuning
- Buried : resistor(4), cap.(9), stripline(RFC 2, Resonator1) : 76% - 부품내장률

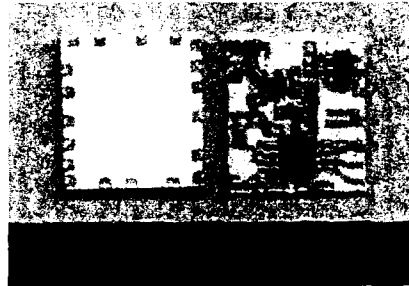
Fabricated sample short-cuts



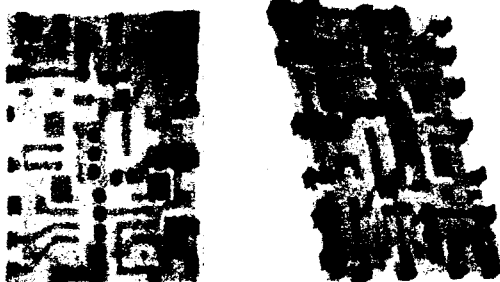
KETI 전자부품연구원
Korea Electronic Technology Institute

LNA/Mixer module for IMT-2K

- Total components = 33 , Layer : 6
- External : FET(1), IC-Up Mixer: RF 2638;
Down CMY210(2), Cap.(8), R(4)
- Buried : Cap.(10), Inductor(8) : 54% - 부품내장률



LNA/Mixer 모듈 시작품



LNA/Mixer 모듈의 X-ray 3차원 투시 사진

KETI 전자부품연구원
Korea Electronic Technology Institute

Bluetooth module comparison (1)

	<p>National Semiconductor</p> <p>Embedded Antenna Front-end filter Rx/Tx Balun PA VCO & Loopfilter Image-rejection filter</p>
	<p>ERICSSON</p> <p>Embedded Antenna filter Rx/Tx Balun</p>
	<p>agere systems</p> <p>Embedded Antenna filter Rx/Tx Balun LoopFilter VCO resonator</p>

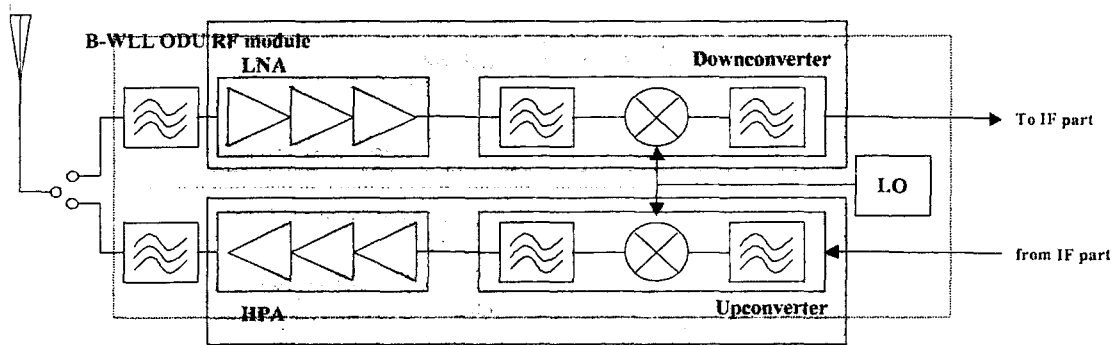
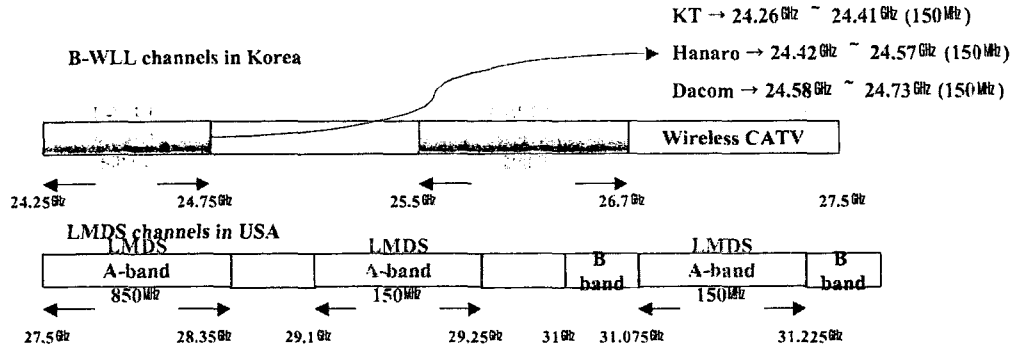
KE TI 전자부품연구원
Korea Electronic Components Research Institute

Bluetooth module comparison (2)

<p>UNIVERSITY OF ARKANSAS</p> <p>Embedded Front-end filter Rx/Tx Balun Loopfilter Image-rejection filter</p>	
<p>z e c a l</p> <p>"Z-strate" Substrate 이용 ; Direct Copper Plating on 90% Al ; Bare-chip or flip-chip 실장에 유리</p>	
<p>MOTOROLA</p> <p>* Zero-Tf Dielectric(T 2000) 이용 * Satellite Rx Front-end module 제작 Embedded 18 Capacitors & 9 TL/Coil External PA, VCO, Transceiver</p>	<p>Embedded solution</p>

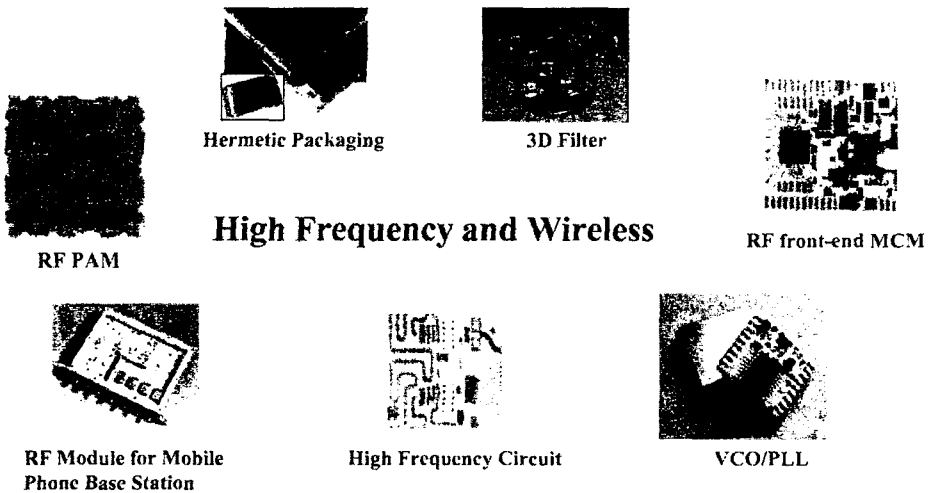
KE TI 전자부품연구원
Korea Electronic Components Research Institute

Our new challenge : B-WLL



KEITI 전자부품연구원
 Korea Electronics Technology Institute

Multilayer ceramic application (1)



KEITI 전자부품연구원
 Korea Electronics Technology Institute

Multilayer ceramic application (2)

○ Automotive : Throttle-valve Module (ETM) circuit, Car ABS, Automotive Engine Control
Advanced Continuously Variable Transmission (CVT) Controller, New-Generation Airbag Sensors



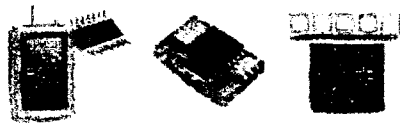
Military : Remote Terminals (multiplex circuits),
Helicopter Module



Medical : Hearing Aid Circuit , Dental Bite Sensors



Industrial and Power : Portable LAN Tester, Multilayer Hybrid Device, DC/DC Power Module



KE TI 전자부품연구원
Korea Electronic Technology Institute

Conclusions

- Embedded Passives
- Embedded Passives & Actives
- Embedded MEMS Package
- Embedded Optical Devices
- Millimeter Wave Package etc.

KE TI 전자부품연구원
Korea Electronic Technology Institute